TOSHIBA Multi-Chip Transistor Silicon NPN / PNP Epitaxial Type

TPC6902

High-Speed Switching Applications MOS Gate Drive Applications

NPN and PNP transistors are mounted on a compact and slim package.

High DC current gain : NPN h_{FE} = 200 to 500 (I_C = 0.2 A)

: PNP h_{FE} = 200 to 500 (I_{C} = -0.2 A)

Low collector-emitter saturation voltage

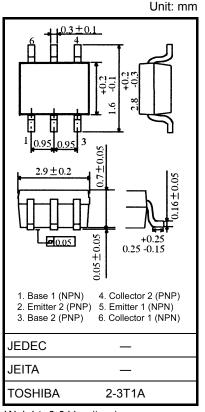
: NPN $V_{CE (sat)} = 0.14 \text{ V (max)}$: PNP $V_{CE (sat)} = -0.2 \text{ V (max)}$

High-speed switching : NPN t_f = 45 ns (typ.)

: PNP $t_f = 40 \text{ ns (typ.)}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating		Unit	
		Symbol	NPN	PNP	Offic	
Collector-base voltage	V _{CBO}	60	- 30	V		
Collector-emitter voltage		V _{CEX}	50	- 30	V	
		V _{CEO}	30	- 30	V	
Emitter-base voltage	V _{EBO}	7	- 7	V		
Collector current (Note 1)	DC	IC	2.0	- 1.7	Α	
	Pulse	I _{CP}	8.0	- 8.0	Α	
Base current	Base current			- 0.5	Α	
Collector power dissipation (t=10 s) (Note 2)	Single-device operation	P _C	1.0		W	
Collector power dissipation (DC) (Note 2)	Single-device operation	P _C	0.7		V	
	Single-device value at dual operation	PC	0.6		V V	
Thermal resistance, junction to ambient (t=10 s) (Note 2)	Single-device operation	R _{th (j-a)}	125		°C/W	
Thermal resistance, junction to ambient (DC) (Note 2)	Single-device operation	R _{th (j-a)}	178		°C/W	
	Single-device value at dual operation	R _{th (j-a)}	208			
Junction temperature	Tj	150		°C		
Storage temperature range		T _{stg}	-55 to 150		°C	



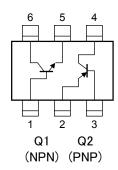
Weight: 0.011 g (typ.)

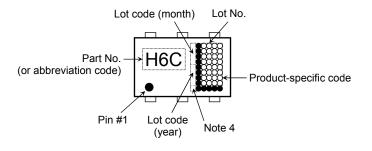
- Note 1: Ensure that the junction temperature does not exceed 150°C.
- Note 2: Mounted on an FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm²)
- Note 3: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Figure 1. Circuit configuration (top view)

Figure 2. Marking





Note 4: A dot marking identifies the indication of product Labels. [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

TPC6902



Electrical Characteristics (Ta = 25°C): NPN

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	$V_{CB} = 60 \text{ V}, I_{E} = 0$	_	_	100	nA
Emitter cut-off current		I _{EBO}	V _{EB} = 7 V, I _C = 0	_	_	100	nA
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = 10 \text{ mA}, I_B = 0$	30	_	_	V
DC current gain		h _{FE} (1)	V _{CE} = 2 V, I _C = 0.2 A	200	_	500	
		h _{FE} (2)	$V_{CE} = 2 \text{ V}, I_{C} = 0.6 \text{ A}$	125	_	_	
		h _{FE} (3)	V _{CE} = 2 V, I _C = 2 A	50	_	_	
Collector-emitter saturation voltage		V _{CE} (sat)	$I_C = 0.6 \text{ A}, I_B = 20 \text{ mA}$	_	_	0.14	V
Base-emitter saturation voltage		V _{BE (sat)}	$I_C = 0.6 \text{ A}, I_B = 20 \text{ mA}$	_	_	1.1	V
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	14	_	pF
Switching time	Rise time	t _r	See Figure 1 circuit diagram. $V_{CC}\approx 18~V,~R_L=30~\Omega$ $I_{B1}=I_{B2}=20~mA$	_	45	_	ns
	Storage time	t _{stg}		_	580	_	
	Fall time	t _f		_	45	_	

Electrical Characteristics (Ta = 25°C): PNP

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = - 30 V, I _E = 0	_	_	- 100	nA
Emitter cut-off current		I _{EBO}	V _{EB} = - 7 V, I _C = 0	_	_	- 100	nA
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-30	_	_	٧
DC current gain		h _{FE} (1)	V _{CE} = - 2 V, I _C = - 0.2 A	200	_	500	
		h _{FE} (2)	V _{CE} = - 2 V, I _C = - 0.6 A	125	_	_	
		h _{FE} (3)	V _{CE} = - 2 V, I _C = -2A	50	_	_	
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = - 0.6 A, I _B = - 20 mA	_	_	- 0.2	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = - 0.6 A, I _B = - 20 mA	_	_	- 1.1	V
Collector output capacitance		C _{ob}	V _{CB} = - 10 V, I _E = 0, f = 1 MHz	_	16.5	_	pF
Switching time	Rise time	t _r	See Figure 2 circuit diagram. $V_{CC} \approx \text{- 18V}, R_L = 30 \Omega, \\ I_{B1} = I_{B2} = 20 \text{mA}$	_	40	_	
	Storage time	t _{stg}		_	280	_	ns
	Fall time	t _f		_	40	_	

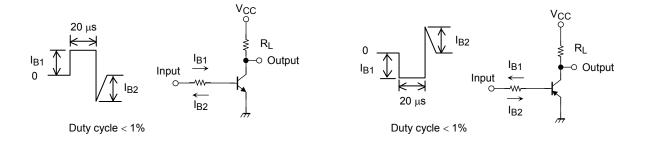
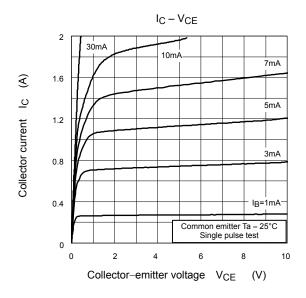


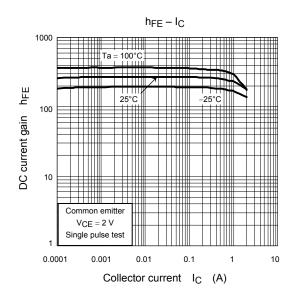
Figure 1 Switching Time Test Circuit & Figure 2 Switching Time Test Circuit & Timing Chart (NPN)

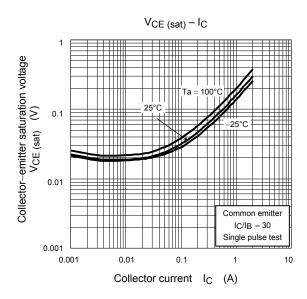
Timing Chart (PNP)

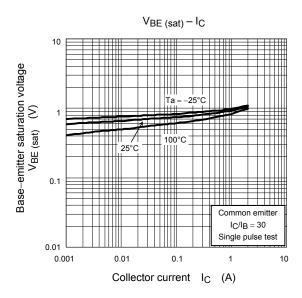
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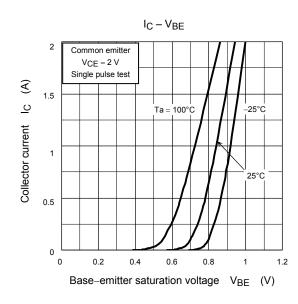
NPN

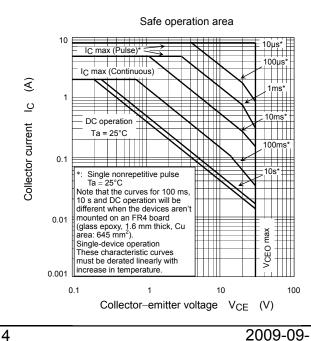




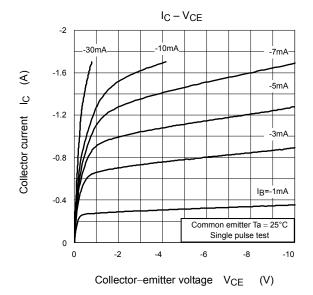


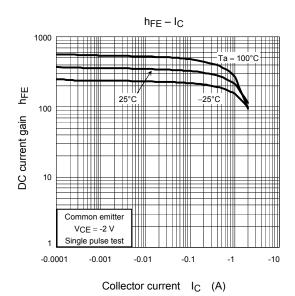


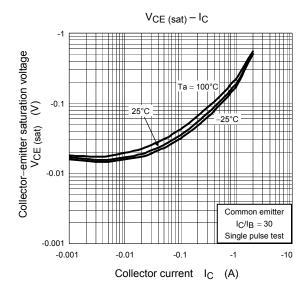


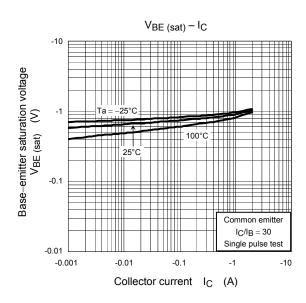


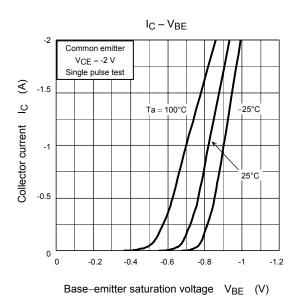
PNP

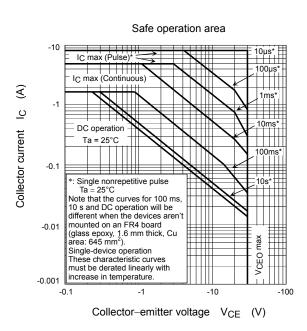






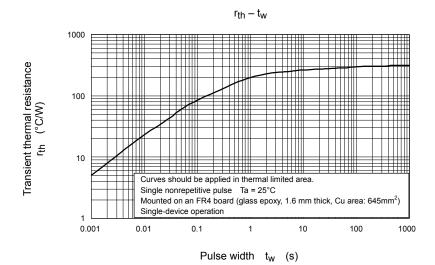




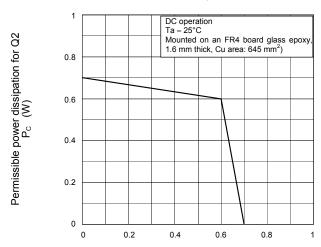


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Common



Permissible Power Dissipation for Simultaneous Operation



Permissible power dissipation for Q1 $$P_{\text{C}}$$ (W)

Collector power dissipation at the single-device operation is 0.7W max.
Collector power dissipation at the single-device value at dual operation is 0.6W max.
Collector power dissipation at the dual operation is set to 1.2W max.

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